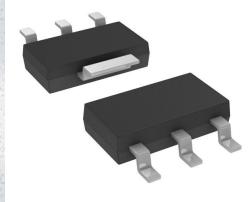


NSS1C201MZ4T1G Datasheet

www.digi-electronics.com

Μ



DiGi Electronics Part Number	NSS1C201MZ4T1G-DG
Manufacturer	onsemi
Aanufacturer Product Number	NSS1C201MZ4T1G
Description	TRANS NPN 100V 2A SOT223
Detailed Description	Bipolar (BJT) Transistor NPN 100 V 2 A 100MHz 800 mW Surface Mount SOT-223 (TO-261)

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
NSS1C201MZ4T1G	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	2 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
100 V	180mV @ 200mA, 2A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA (ICBO)	120 @ 500mA, 2V
Power - Max:	Frequency - Transition:
800 mW	100MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223 (TO-261)
Base Product Number:	
NSS1C201	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	

nsemi

100 V, 2.0 A, Low V_{CE(sat)} **NPN Transistor** NSS1C201MZ4. NSV1C201MZ4

onsemi's e²PowerEdge family of low V_{CE(sat)} transistors are miniature surface mount devices featuring ultra low saturation voltage (V_{CE(sat)}) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers. Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Мах	Unit
Collector-Emitter Voltage	V _{CEO}	100	Vdc
Collector-Base Voltage	V _{CBO}	140	Vdc
Emitter-Base Voltage	V _{EBO}	7.0	Vdc
Collector Current – Continuous	Ι _C	2.0	А
Collector Current – Peak	I _{CM}	3.0	A

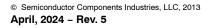
THERMAL CHARACTERISTICS

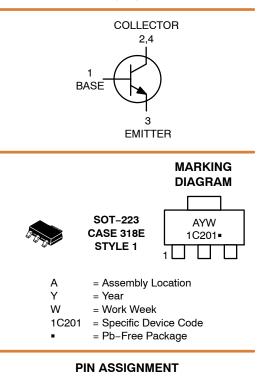
Characteristic	Symbol	Мах	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D (Note 1)	800 6.5	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 1)	155	°C/W
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D (Note 2)	2.0 15.6	W mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	64	°C/W
Total Device Dissipation (Single Pulse < 10 sec.)	P _{Dsingle} (Note 3)	710	mW
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

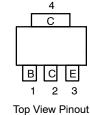
FR-4 @ 7.6 mm², 1 oz. copper traces.
FR-4 @ 645 mm², 1 oz. copper traces.

3. Thermal response.





100 VOLTS, 2.0 AMPS NPN LOW V_{CE(sat)} TRANSISTOR



ORDERING INFORMATION

Device	Package	Shipping [†]
NSS1C201MZ4T1G NSV1C201MZ4T1G	SOT–223 (Pb–Free)	1000/ Tape & Reel
NSS1C201MZ4T3G	SOT-223 (Pb-Free)	4000/ Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NSS1C201MZ4T1G onsemi TRANS NPN 100V 2A SOT223

NSS1C201MZ4, NSV1C201MZ4

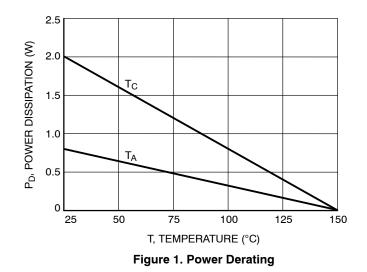
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				-	
Collector – Emitter Breakdown Voltage ($I_C = 10 \text{ mAdc}, I_B = 0$)	V _{(BR)CEO}	100			Vdc
Collector – Base Breakdown Voltage ($I_C = 0.1 \text{ mAdc}, I_E = 0$)	V _{(BR)CBO}	140			Vdc
Emitter – Base Breakdown Voltage ($I_E = 0.1 \text{ mAdc}, I_C = 0$)	V _{(BR)EBO}	7.0			Vdc
Collector Cutoff Current (V _{CB} = 140 Vdc, $I_E = 0$)	I _{CBO}			100	nA
Emitter Cutoff Current (V _{EB} = 6.0 Vdc)	I _{EBO}			50	nA
ON CHARACTERISTICS				-	
DC Current Gain (Note 4)	h _{FE}				

	UFE	150 120 80 40		360	
	V _{CE(sat)}			0.030 0.060 0.100 0.180	V
Base – Emitter Saturation Voltage (Note 4) $(I_C = 1.0 \text{ A}, I_B = 0.100 \text{ A})$	V _{BE(sat)}			1.10	V
Base – Emitter Turn–on Voltage (Note 4) (I_C = 1.0 A, V_{CE} = 2.0 V)	V _{BE(on)}			0.850	V
Cutoff Frequency (I_C = 100 mA, V_{CE} = 5.0 V, f = 100 MHz)	f _T		100		MHz
Input Capacitance (V _{EB} = 0.5 V, f = 1.0 MHz)	Cibo		305		pF
Output Capacitance (V _{CB} = 3.0 V, f = 1.0 MHz)	Cobo		22		pF

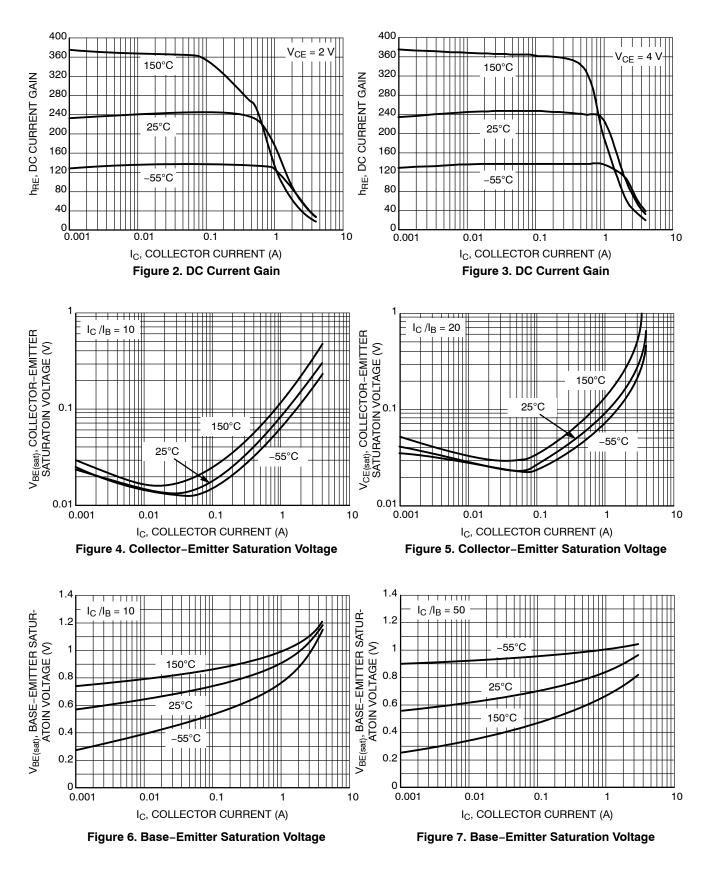
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle ≤ 2%.

TYPICAL CHARACTERISTICS



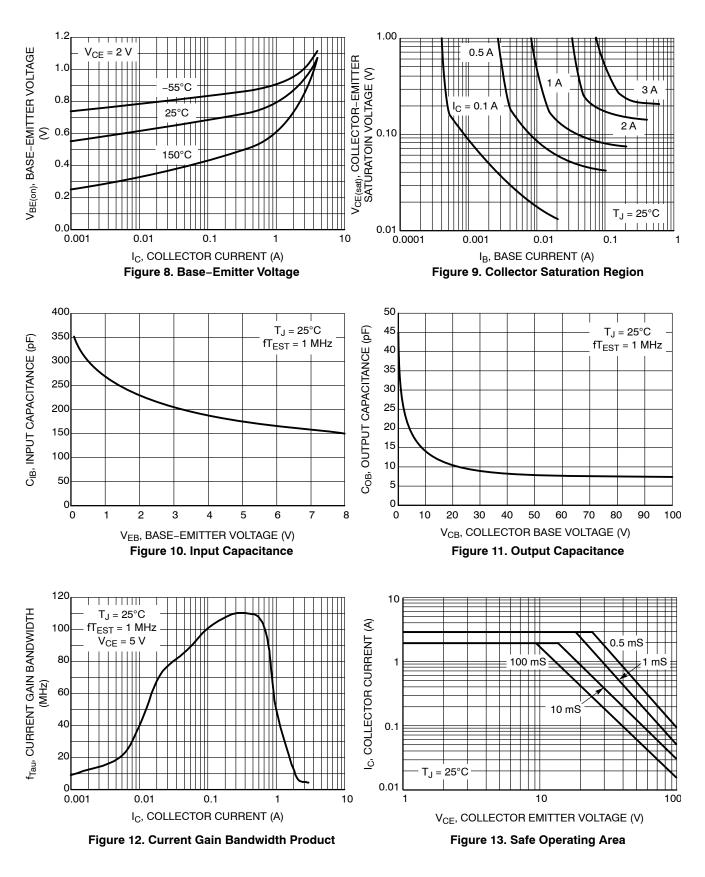
NSS1C201MZ4, NSV1C201MZ4

TYPICAL CHARACTERISTICS



NSS1C201MZ4, NSV1C201MZ4

TYPICAL CHARACTERISTICS



NSEM

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

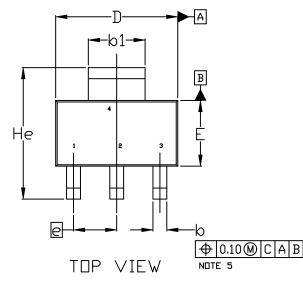


SOT-223 (TO-261) CASE 318E-04 **ISSUE R**

SEE DETAIL A

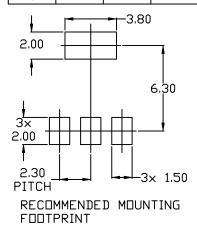
FRONT VIEW

DATE 02 OCT 2018



- NDTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSIONS D & E DO NOT INCLUDE MOLD з. FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
- 4. DATUMS A AND B ARE DETERMINED AT DATUM H.
- AI IS DEFINED AS THE VERTICAL DISTANCE 5. FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
- POSITIONAL TOLERANCE APPLIES TO 6. DIMENSIONS & AND b1.

	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
A	1.50	1.63	1.75	
A1	0.02	0.06	0.10	
b	0.60	0.75	0.89	
b1	2.90	3.06	3.20	
с	0.24	0.29	0.35	
D	6.30	6.50	6.70	
E	3.30	3.50	3.70	
e		2.30 B2C	;	
L	0.20			
L1	1.50	1.75	2.00	
He	6.70	7.00	7.30	
θ	0*		10*	

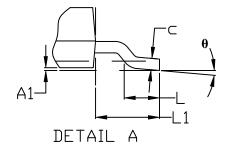


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DESCRIPTION:	SOT-223 (TO-261)		PAGE 1 OF 2

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н Α 0.10 C

SIDE VIEW



SOT-223 (TO-261) CASE 318E-04 ISSUE R

DATE 02 OCT 2018

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. ANODE 2. CATHODE 3. NC 4. CATHODE	STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 4: Pin 1. Source 2. Drain 3. Gate 4. Drain	STYLE 5: PIN 1. DRAIN 2. GATE 3. SOURCE 4. GATE
Style 6: Pin 1. Return 2. Input 3. Output 4. Input	STYLE 7: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 4. CATHODE	STYLE 8: CANCELLED	Style 9: Pin 1. Input 2. ground 3. logic 4. ground	STYLE 10: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE
STYLE 11: PIN 1. MT 1 2. MT 2 3. GATE 4. MT 2	STYLE 12: PIN 1. INPUT 2. OUTPUT 3. NC 4. OUTPUT	STYLE 13: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR		

GENERIC MARKING DIAGRAM*



- A = Assembly Location
- Y = Year
- W = Work Week
- XXXXX = Specific Device Code
- = Pb-Free Package
- (Note: Microdot may be in either location) *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	SOT-223 (TO-261)		PAGE 2 OF 2		

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